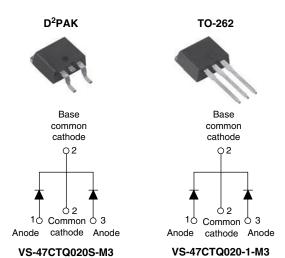


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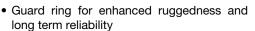
High Performance Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY					
I _{F(AV)}	2 x 20 A				
V_{R}	20 V				
V _F at I _F	0.34 V				
I _{RM} max.	310 mA at 125 °C				
T _J max.	150 °C				
E _{AS}	18 mJ				
Package	TO-263AB (D ² PAK), TO-262AA				
Diode variation	Common cathode				

FEATURES

- 150 °C T_J operation
- Center tap configuration
- · Optimized for 3.3 V application
- Ultralow forward voltage drop
- · High frequency operation





- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for 3.3 V output power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATING	MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	40	Α					
V _{RRM}		20	V					
I _{FSM}	t _p = 5 μs sine	1000	Α					
V _F	20 A _{pk} , T _J = 125 °C	0.34	V					
TJ		-55 to 150	°C					

VOLTAGE RATINGS							
PARAMETER	UNITS						
Maximum DC rayaraa yaltaga	W	125 °C	20	V			
Maximum DC reverse voltage	V _R	150 °C	10	V			



VS-47CTQ020S-M3, VS-47CTQ020-1-M3

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average	Maximum average per leg		50 % duty cycle at T _C = 135 °C	rootongular wayafarm	20			
forward current per device		I _{F(AV)}	50 % duty cycle at 1 _C = 135 C	40				
Maximum peak one cycle non-repetitive surge current per leg			5 μs sine or 3 μs rect. pulse	Following any rated load	1000	Α		
		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	250			
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25 ^{\circ}\text{C}$, $I_{AS} = 3 \text{A}$, $L = 3 \text{mH}$		18	mJ		
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	Α		

ELECTRICAL SPECIFICATION	ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST (TEST CONDITIONS				
		20 A	T 05 °C	0.45			
		40 A	T _J = 25 °C	0.51			
Maximum forward voltage drop per leg	V (1)	20 A	T 105 %	0.34	W		
	V _{FM} ⁽¹⁾	40 A	T _J = 125 °C	0.44	V		
		20 A	T 150 °C	0.31			
		40 A	T _J = 150 °C	0.42			
	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = 5 V	60			
			V _R = 3.3 V	45	mA		
Maximum reverse leakage		T _J = 150 °C	V _R = 10 V	306			
current per leg		T _J = 25 °C	V Balady	3			
		T _J = 125 °C	V_R = Rated V_R	310			
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.188	V		
Forward slope resistance	r _t			5.9	mΩ		
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal rai	nge 100 kHz to 1 MHz), 25 °C	3000	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.5	nΗ		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHAI	NICAL SPI	ECIFICAT	IONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage	ge	T _J , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		D	DC operation	1.5	
		R_{thJC}	DC operation	0.75	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque minimum maximum				6 (5)	kgf · cm
				12 (10)	(lbf · in)
Marking device			Case style D ² PAK	47CTQ0)20S
			Case style TO-262	47CTQ0)20-1



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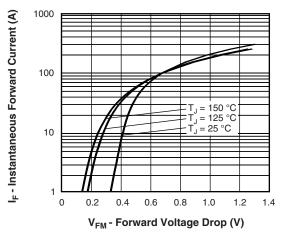


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

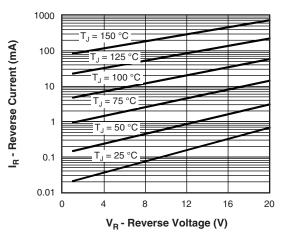


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

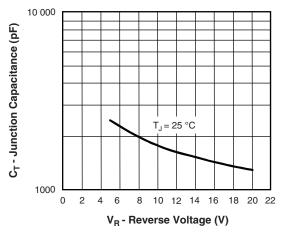


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

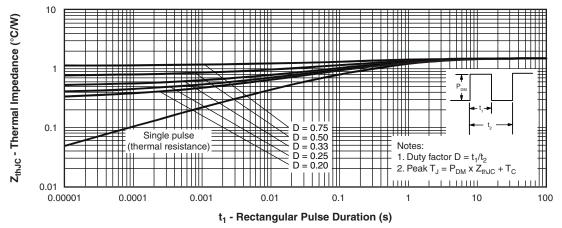


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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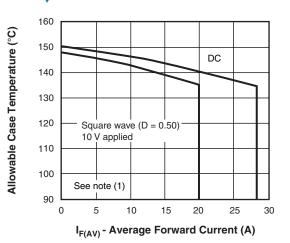


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

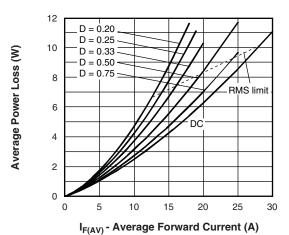


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

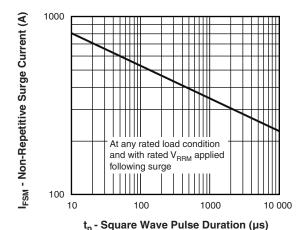


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

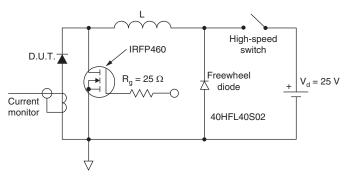


Fig. 8 - Unclamped Inductive Test Circuit

Note

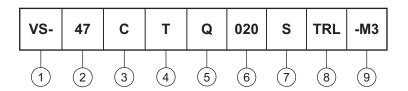
(1) Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 A)

3 - Circuit configuration: C = Common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (020 = 20 V)

7 - • S = D^2PAK

• -1 = TO-262

8 - • None = Tube

• TRL = Tape and reel (left oriented - for D²PAK only)

• TRR = Tape and reel (right oriented - for D²PAK only)

9 - -M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-47CTQ020S-M3	50	1000	Antistatic plastic tubes				
VS-47CTQ020STRR-M3	800	800	13" diameter reel				
VS-47CTQ020STRL-M3	800	800	13" diameter reel				
VS-47CTQ020-1-M3	50	1000	Antistatic plastic tubes				

	LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046					
Dimensions	TO-262AA	www.vishay.com/doc?95419					
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?95032					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	S SYMBOL		MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

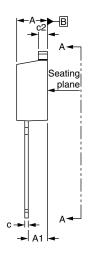
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

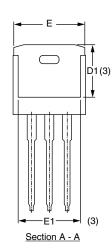


Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



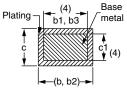


⊕ 0.010**⋒**|A**⋒**|B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CYMPOL	MILLIN	METERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	=	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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